

CentralTM Semiconductor Corp.

145 Adams Avenue, Hauppauge, NY 11788 USA
Tel: (631) 435-1110 • Fax: (631) 435-1824

Manufacturers of World Class Discrete Semiconductors

2N5232A

NPN SILICON TRANSISTOR

JEDEC TO-92 CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N5232A type is a NPN Silicon Planar Epitaxial Transistors designed for low noise amplifier applications.

MAXIMUM RATINGS (T_A = 25°C)

	SYMBOL		UNITS
Collector-Base Voltage	V _{CB0}	70	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Continuous Collector Current	I _C	100	mA
Power Dissipation	P _D	625	mW
Operating and Storage			
Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	θ _{JA}	0.2	°C/mW

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I _{CBO}	V _{CB} = 50V			30	nA
I _{CBO}	V _{CB} = 50V, T _A = 100°C			10	μA
I _{CES}	V _{CB} = 50V			30	nA
I _{EBO}	V _{EB} = 5.0V			50	nA
BV _{CBO}	I _C = 10μA	70			V
BV _{CEO}	I _C = 10mA	50			V
BV _{EBO}	I _C = 10μA	5.0			V
V _{CE(SAT)}	I _C = 10mA, I _B = 1.0mA		0.125		V
V _{BE(SAT)}	I _C = 10mA, I _B = 1.0mA		0.780		V
V _{BE(ON)}	V _{CE} = 10V, I _C = 2.0mA	0.500	0.900		V
h _{FE}	V _{CE} = 5.0V, I _C = 2.0mA	250	500		
h _{fe}	V _{CE} = 5.0V, I _C = 2.0mA, f = 1.0kHz	250	750		
C _{ob}	V _{CB} = 10V, I _E = 0, f = 1.0MHz			4.0	pF
NF	V _{CE} = 5.0V, I _C = 100μA, R _g = 5kΩ f = 1kHz, BW = 15.7kHz		1.9	5.0	dB

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp.
145 Adams Avenue
Hauppauge, NY 11788 USA
Main Tel: (631) 435-1110
Main Fax: (631) 435-1824
Support Team Fax: (631) 435-3388
www.centrasemi.com

Worldwide Field Representatives:
www.centrasemi.com/wwreps

Worldwide Distributors:
www.centrasemi.com/wwdistributors

For the latest version of Central Semiconductor's **LIMITATIONS AND DAMAGES DISCLAIMER**, which is part of Central's Standard Terms and Conditions of sale, visit: www.centrasemi.com/terms